

CW Power Transistor, 85W

30 - 400 MHz

PH0104-85

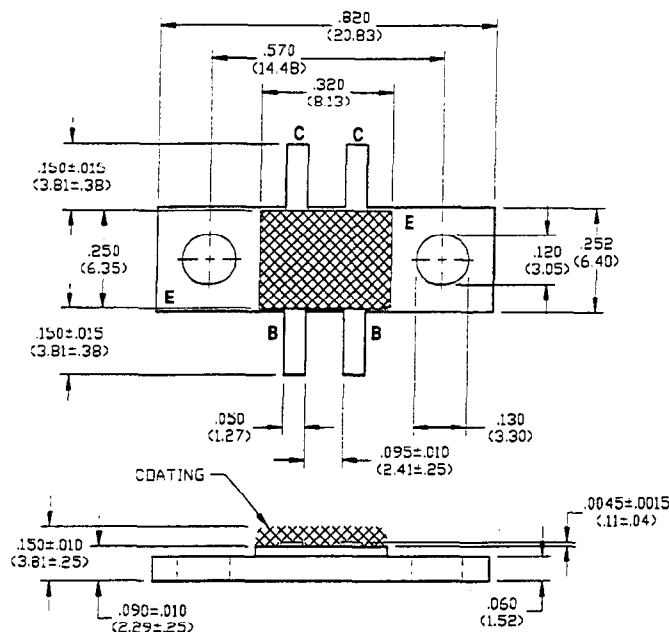
V2.00

Features

- NPN Silicon Power Transistor
- Common Emitter Configuration
- Class AB Broadband Operation
- 85 Watt PEP Output
- Diffused Emitter Ballasting Resistors
- Gold Metallization System
- Proven in Thousands of ARC-182 Airborne Radios

Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	65	V
Emitter-Base Voltage	V_{EBO}	4.0	V
Collector Current (Peak)	I_C	10	A
Power Dissipation	P_D	194	W
Junction Temperature	T_J	200	°C
Storage Temperature	T_{STG}	-40 to +125	°C
Thermal Resistance	θ_{JC}	0.9	°C/W



UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES $\pm .005$
(MILLIMETERS $\pm .13$ MM)

Electrical Characteristics at 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Collector-Emitter Breakdown Voltage	BV_{CES}	65	-	V	$I_C=10$ mA, $V_{BE}=0.0$ V
Base-Emitter Breakdown Voltage	BV_{EBO}	4.0	-	V	$I_E=10$ mA, $I_C=0.0$ A
Collector-Emitter Leakage Current	I_{CES}	-	4	mA	$V_{CE}=30$ V
DC Forward Current Gain	h_{FE}	20	80	-	$V_{CE}=5.0$ V, $I_C=2.0$ A
Input Power	P_{IN}	-	16	W	$V_{CC}=27$ V, $I_{CO}=50$ mA, $P_{OUT}=85$ W, $F=400$ MHz
Power Gain	G_P	7.3	-	dB	$V_{CC}=27$ V, $I_{CO}=50$ mA, $P_{OUT}=85$ W, $F=400$ MHz
Collector Efficiency	η_C	45	-	%	$V_{CC}=27$ V, $I_{CO}=50$ mA, $P_{OUT}=85$ W, $F=400$ MHz
Input Return Loss	RL	9	-	dB	$V_{CC}=27$ V, $I_{CO}=50$ mA, $P_{OUT}=85$ W, $F=400$ MHz
Load Mismatch Tolerance	VSWR-T	-	3:1	-	$V_{CC}=27$ V, $I_{CO}=50$ mA, $P_{OUT}=85$ W, $F=400$ MHz